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## BFG93A; BFG93A/X

NPN 6 GHz wideband transistors

Rev. 05 — 26 November 2007

**Product data sheet** 

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NXP Semiconductors



## BFG93A; BFG93A/X

#### FEATURES

- High power gain
- Low noise figure
- Gold metallization ensures excellent reliability.

#### APPLICATIONS

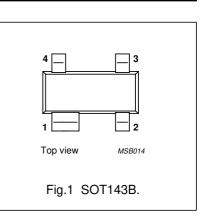
Wideband applications in the UHF and microwave range.

#### DESCRIPTION

NPN transistor in a 4-pin, dual-emitter SOT143B plastic package.

#### PINNING

PIN	DESCRIPTION			
BFG93A				
1	collector			
2	base			
3	emitter			
4	emitter			
BFG93A/X				
1	collector			
2	emitter			
3	base			
4	emitter			



#### MARKING

TYPE NUMBER	CODE
BFG93A	R8%
BFG93A/X	%MX

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-	15	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	12	V
I <sub>C</sub>	collector current (DC)		-	-	35	mA
P <sub>tot</sub>	total power dissipation	$T_s \le 85 \ ^{\circ}C$	-	-	300	mW
C <sub>re</sub>	feedback capacitance	$I_{C} = i_{c} = 0; V_{CB} = 5 V; f = 1 MHz$	-	0.6	-	pF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 30 mA; V <sub>CE</sub> = 5 V; f = 500 MHz	4.5	6	-	GHz
G <sub>UM</sub>	maximum unilateral power gain	$I_C$ = 30 mA; $V_{CE}$ = 8 V; $T_{amb}$ = 25 °C; f = 1 GHz	-	16	-	dB
		$I_C = 30 \text{ mA}; V_{CE} = 8 \text{ V}; T_{amb} = 25 \text{ °C};$ f = 2 GHz	-	10	-	dB
F	noise figure	$ \begin{aligned} \Gamma_{s} &= \Gamma_{opt}; \ \textbf{I}_{C} &= 5 \ \text{mA}; \ \textbf{V}_{CE} &= 8 \ \textbf{V}; \\ T_{amb} &= 25 \ ^{\circ}\text{C}; \ \textbf{f} &= 1 \ \text{GHz} \end{aligned} $	-	1.7	-	dB

## BFG93A; BFG93A/X

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	15	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	12	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	2	V
I <sub>C</sub>	collector current (DC)		_	35	mA
P <sub>tot</sub>	total power dissipation	$T_s \le 85 \ ^{\circ}C$ ; note 1	-	300	mW
T <sub>stg</sub>	storage temperature range		-65	+150	°C
Tj	junction operating temperature		_	175	°C

#### Note

1.  $T_s$  is the temperature at the soldering point of the collector pin.

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	note 1	290	K/W

#### Note

1. T<sub>s</sub> is the temperature at the soldering point of the collector pin.

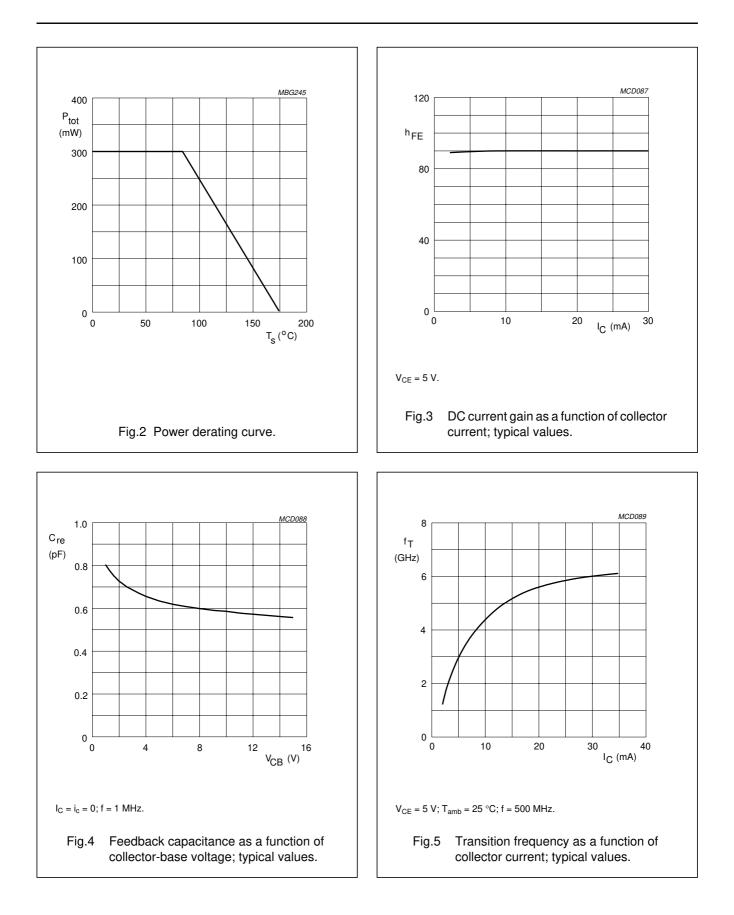
#### CHARACTERISTICS

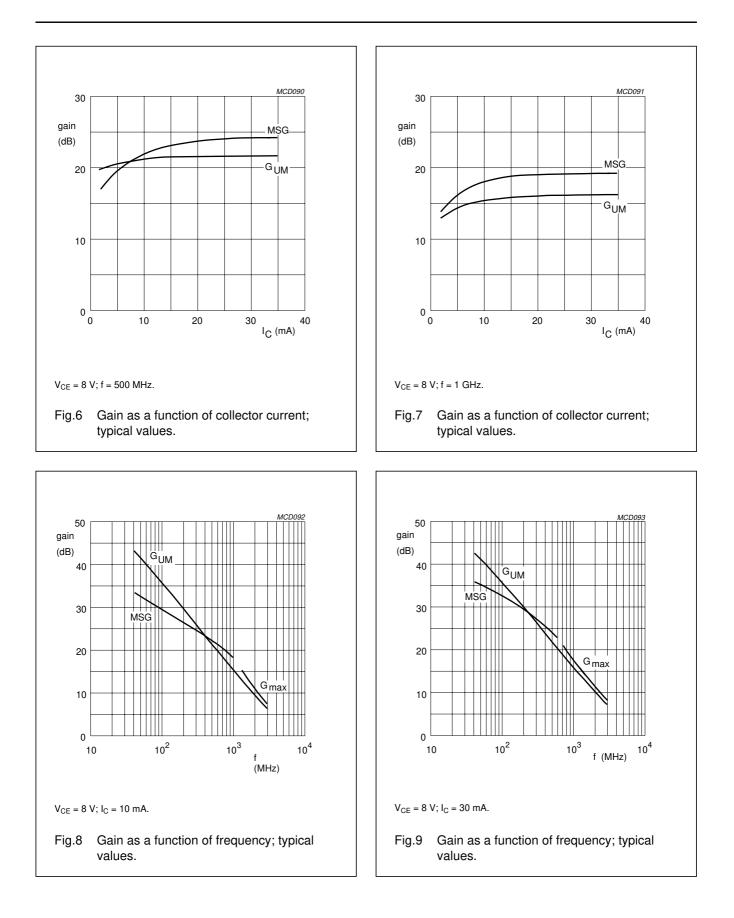
 $T_i = 25 \ ^{\circ}C$  unless otherwise specified.

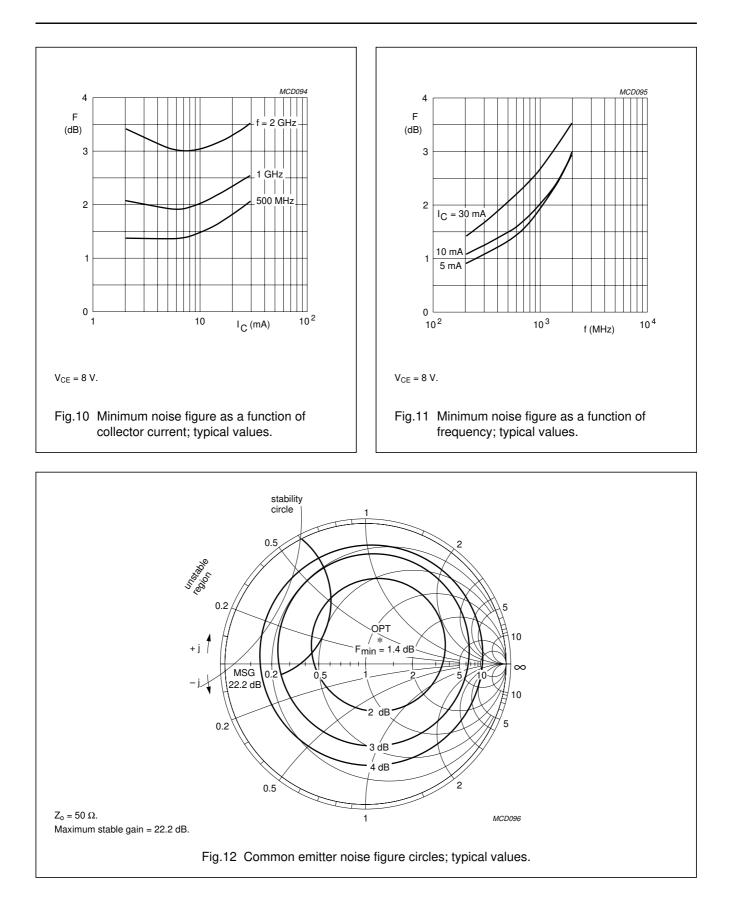
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector leakage current	$I_E = 0; V_{CB} = 5 V$	-	-	50	nA
h <sub>FE</sub>	DC current gain	$I_{C} = 30 \text{ mA}; V_{CE} = 5 \text{ V}$	40	90	-	
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0; V_{CB} = 5 V; f = 1 MHz$	-	0.9	-	pF
Ce	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = 5 V; f = 1 MHz$	-	1.9	-	pF
C <sub>re</sub>	feedback capacitance	$I_{C} = i_{c} = 0; V_{CB} = 5 V; f = 1 MHz$	-	0.6	-	pF
f <sub>T</sub>	transition frequency	$I_{C} = 30 \text{ mA}; V_{CE} = 5 \text{ V}; f = 500 \text{ MHz}$	4.5	6	-	GHz
G <sub>UM</sub>	maximum unilateral power gain; note 1	$I_C$ = 30 mA; $V_{CE}$ = 8 V; $T_{amb}$ = 25 °C; f = 1 GHz	-	16	-	dB
		$I_C$ = 30 mA; $V_{CE}$ = 8 V; $T_{amb}$ = 25 °C; f = 2 GHz	-	10	-	dB
F	noise figure	$ \begin{split} \Gamma_{s} &= \Gamma_{opt}; \ \text{I}_{C} = 5 \ \text{mA}; \ \text{V}_{CE} = 8 \ \text{V}; \\ T_{amb} &= 25 \ ^{\circ}\text{C}; \ \text{f} = 1 \ \text{GHz} \end{split} $	-	1.7	-	dB
		$ \begin{split} \Gamma_{s} &= \Gamma_{opt}; \ \text{I}_{C} = 5 \ \text{mA}; \ \text{V}_{CE} = 8 \ \text{V}; \\ T_{amb} &= 25 \ ^{\circ}\text{C}; \ \text{f} = 2 \ \text{GHz} \end{split} $	_	2.3	-	dB

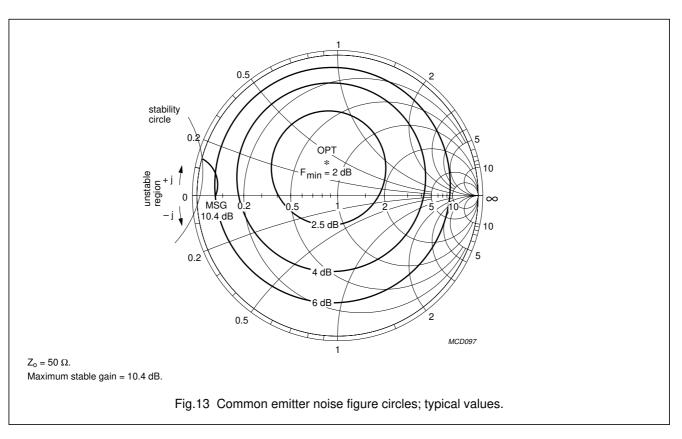
#### Note

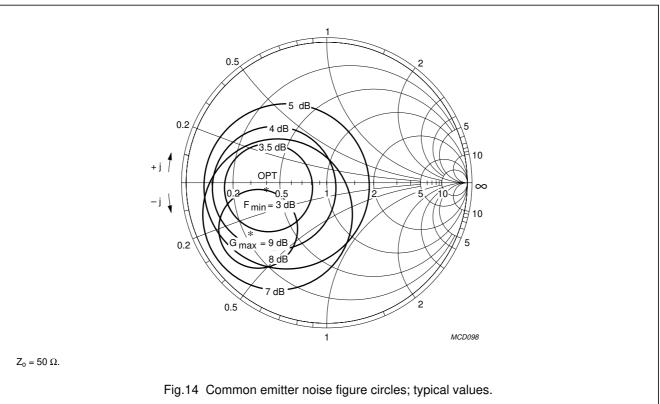
1.  $G_{UM}$  is the maximum unilateral power gain, assuming  $S_{12}$  is zero and  $G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} dB.$ 

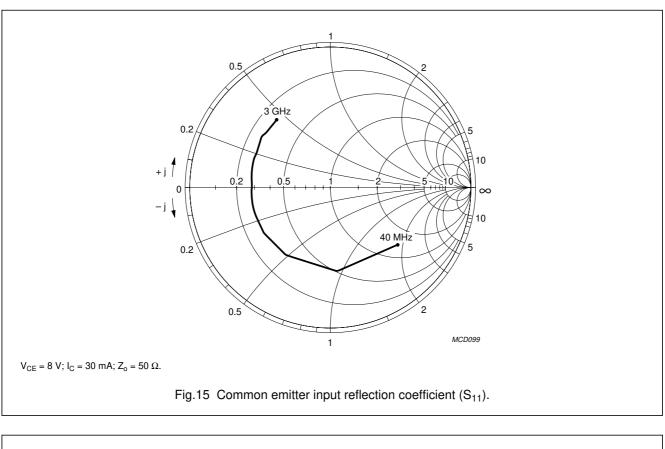


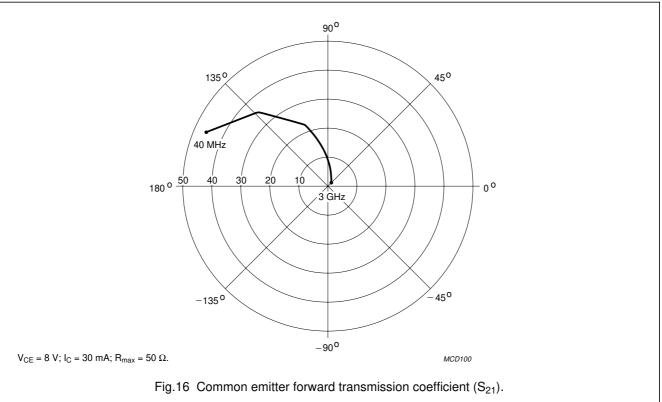


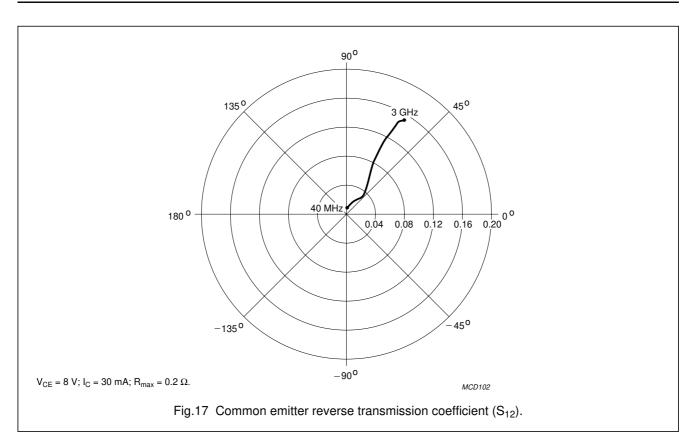


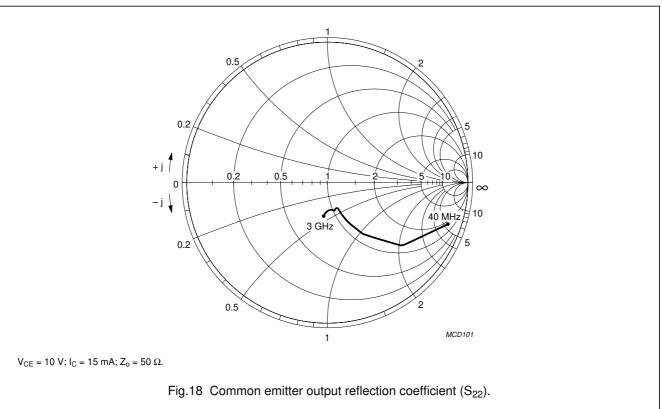












#### BFG93A; BFG93A/X

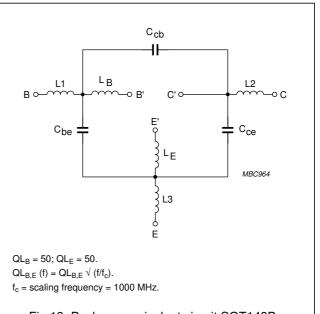
#### SPICE parameters for BFR91A(/X) die

SEQUENCE No.	PARAMETER	VALUE	UNIT
1	IS	1.328	fA
2	BF	102.0	_
3	NF	1.000	_
4	VAF	51.90	V
5	IKF	8.155	А
6	ISE	13.90	fA
7	NE	15.12	_
8	BR	17.69	_
9	NR	994.0	m
10	VAR	3.280	V
11	IKR	10.00	А
12	ISC	1.043	aA
13	NC	1.189	_
14	RB	10.00	Ω
15	IRB	1.000	μA
16	RBM	10.00	Ω
17	RE	763.6	mΩ
18	RC	9.000	Ω
19 (note 1)	ХТВ	0.000	_
20 (note 1)	EG	1.110	EV
21 (note 1)	ХТІ	3.000	_
22	CJE	2.032	pF
23	VJE	600.0	mV
24	MJE	290.0	m
25	TF	6.557	ps
26	XTF	38.97	_
27	VTF	10.93	V
28	ITF	521.0	mA
29	PTF	0.000	deg
30	CJC	1.003	pF
31	VJC	340.8	mV
32	MJC	194.2	m
33	XCJC	120.0	m
34	TR	3.073	ns
35 (note 1)	CJS	0.000	F

SEQUENCE No.	PARAMETER	VALUE	UNIT
36 (note 1)	VJS	750.0	mV
37 (note 1)	MJS	0.000	-
38	FC	800.0	m

#### Note

1. These parameters have not been extracted, the default values are shown.



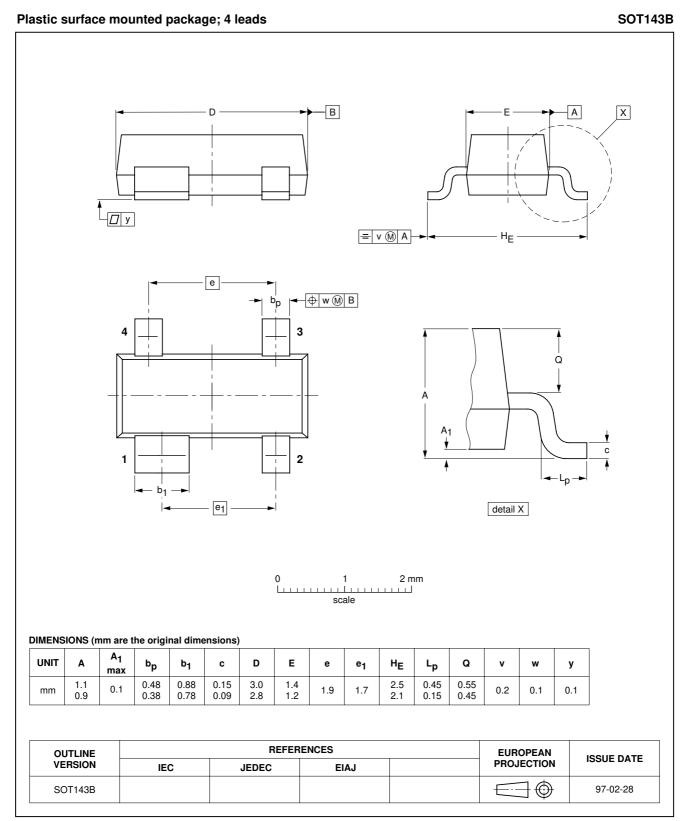
#### Fig.19 Package equivalent circuit SOT143B.

#### List of components (see Fig.19)

DESIGNATION	VALUE	UNIT
C <sub>be</sub>	84	fF
C <sub>cb</sub>	17	fF
C <sub>ce</sub>	191	fF
L1	0.12	nH
L2	0.21	nH
L3	0.06	nH
L <sub>B</sub>	0.95	nH
LE	0.40	nH

## BFG93A; BFG93A/X

#### PACKAGE OUTLINE



#### Legal information

#### Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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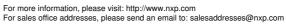
## **Revision history**

Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BFG93A_X_N_5	20071126	Product data sheet	-	BFG93A_X_4	
Modifications:	<ul> <li>Marking tab</li> </ul>	le on page 2; changed code			
BFG93A_X_4 (9397 750 04351)	19980923	Product specification	-	BFG93SERIES_3	
BFG93SERIES_3	19950925	Product specification	-	BFG93SERIES_2	
BFG93SERIES_2	-	Product specification	-	BFG93_SERIES_1	
BFG93_SERIES_1	-	-	-	-	

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